

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

### DECLARATION FOR PATENT APPLICATION

As the below named inventors, we hereby declare that:

Our residence, post office address and citizenship are as stated below next to our names.

We believe we are the original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled:

# METHOD AND APPARATUS FOR PLASMA ETCHING A WAFER.

The specification of which is attached hereto.

We hereby state that we have reviewed and understand the contents of the above identified specification, including the claims, as amended by an amendment, if any, specifically referred to in this oath or declaration.

We acknowledge the duty to disclose all information known to me which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56.

We hereby claim foreign priority benefits under Title 35, United States Code, § 119/365 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

#### None

We hereby claim the benefit under Title 35, United States Code, § 120/365 of any United States and PCT international application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, we acknowledge the duty to disclose all information known to us to be material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56(a) which became available between the filing date of the prior application and the national or PCT international filing date of this application:

None

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We hereby declare that all statements made herein of our own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Please address all correspondence to Thomas J. D'Amico of Dickstein Shapiro Morin & Oshinsky LLP located at 2101 L Street, NW, Washington, DC 20037-1526. Telephone calls should be made to Thomas J. D'Amico by dialing (202) 828-2232.

Z Date 5-5-98

Full name of 1st joint inventor: Rodney C. Langley

Inventor's signature

Residence: Boise, Idaho

Citizenship: United States of America

Post Office Address: 5930 Hollilynn, Boise, Idaho

Full name of 2nd joint inventor: David R. Johnson

Inventor's signature

Residence: Meridian, Idaho

Citizenship: United States of America

Post Office Address: 3199 S. Selatair Place, Meridian, Idaho

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Full name of 3rd joint inventor: Willard L. Hofer

Inventor's signature will de J. Holy Date 5/5/98

Residence: Boise, Idaho

Citizenship: United States of America

Post Office Address: 469 S. Emily, Boise, Idaho 83709

PATENT

Docket No.: M4065.018/P018

Micron No.: 97-918

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

1-511 U.S.PTO

Patent Application Inventors: Rodney C.Langley, David R. Johnson; Willard L. Hofer

Serial No.: Not Yet Assigned

Group Art Unit: Not Yet

Assigned

Filed: Concurrently Herewith

Examiner: Not Yet Assigned

For: METHOD AND APPARATUS FOR

PLASMA ETCHING A WAFER

# POWER OF ATTORNEY BY ASSIGNEE AND CERTIFICATE BY ASSIGNEE UNDER 37 CFR \$ 3.73(b)

Micron Technology. Inc., assignee of the entire right, title and interest in the above-identified application by virtue of the assignment attached hereto (which is also being submitted concurrently for recordation), hereby appoints the attorneys and agents of the firm of Dickstein Shapiro Morin & Oshinsky LLP located at 2101 L Street, NW, Washington, DC 20037-1526, listed as follows: Gary M. Hoffman, 26,411; Thomas J. D'Amico, 28,371; Donald A. Gregory, 28,954; James W. Brady, Jr., 32,115; Jon D. Grossman, 32,699; Mark J. Thronson, 33,082; Laurence D. Fisher, 37,131; John R. Fuisz, 37,327; Juliana Haydoutova, P43,313; James M. Heintz, P41,828; Herbert V. Kerner, P42,721; Gianní Minutoli,

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41,198; Eric Oliver, 35,307; William E. Powell, III, 39,803;
James M. Silbermann, 40,413; Richard Veltman, 36,957 and Darius
Gambino, 41,472, and also attorneys Michael L. Lynch, 30,871; Lia
M. Pappas, 34,095; W. Eric Webostad, 35,406; and Charles B.
Brantley, II, 38,086 of Micron Technology, Inc. as its attorneys
with full power of substitution to prosecute this application and
to transact all business in the Patent and Trademark Office in
connection therewith.

The assignee certifies that the above-identified assignment has been reviewed and to the best of the assignee's knowledge and belief, title is in the assignee.

Please direct all correspondence regarding this application to the following:

Thomas J. D'Amico, Esq.
Dickstein Shapiro Morin & Oshinsky LLP
2101 L Street, NW
Washington, D.C. 20037-1526
Telephone: (202) 828-2232
Facsimile: (202) 887-0689

MICRON TECHNOLOGY, INC.

Michael L. Lynch Chief Patent Counsel

Registration No. 30,871

Dated: 34 6,1998

# ASSIGNMENT AND AGREEMENT

For value received, we, Rodney C. Langley, David R. Johnson, Willard L. Hofer hereby sell, assign and transfer to Micron Technology Inc., a corporation of the State of Delaware, having an office at 8000 S. Federal Way, Boise, Idaho 83706-9632, U.S.A., and its successors, assigns and legal representatives, the entire right, title and interest, for the United States of America, in and to certain inventions related to an invention entitled METHOD AND APPARATUS FOR PLASMA ETCHING A WAFER;

described in an application for Letters Patent of the United States, executed by us of even date herewith, and all the rights and privileges in said application and under any and all Letters Patent that may be granted in the United State for said inventions; and we also concurrently hereby sell, assign and transfer to Micron Technology, Inc. the entire right, title and interest in and to said inventions for all countries foreign to the United States, including all rights of priority arising from the application aforesaid, and all the rights and privileges under any and all forms of protection, including Letters Patent, that may be granted in said countries foreign to the United States for said inventions.

We authorize Micron Technology, Inc. to make application for such protection in its own name and maintain such protection in any and all countries foreign to the United States, and to invoke and claim for any application for patent or other form of protection for said inventions, without further authorization from us, any and all benefits, including the right of priority provided by any and all treaties, conventions, or agreements.

We hereby consent that a copy of this assignment shall be deemed a full legal and formal equivalent of any document which may be required in any country in proof of the right of Micron Technology, Inc. to apply for patent or other form of protection for said inventions and to claim the aforesaid benefit of the right of priority.

We request that any and all patents for said inventions be issued to Micron Technology, Inc. in the United States and in all countries foreign to the United States, or to such nominees as Micron Technology, Inc. may designate.

· ",

We agree that, when requested, we shall, without charge to Micron Technology, Use agree that, when requested, we shall, without charge to Micron Technology, and the said application of processary, desirable or convenient in connection with said applications, patents, or other forms of protection.		
Rodney C. Hangley		
Date: 5-5-98		
United States of America ) State of <u>Odaho</u> )ss.: County of <u>Odaho</u> )		
On this 5 day of , 1998, before me personally came Rodney C. Langley, to me known to be the individual described in and who executed the foregoing instrument, and acknowledged execution of the same.		
Notary Public  Notary Public  Notary Public		
****		

	David R. Johnson
Date: 5-5-98	
United States of America  State of Odaho )ss.:  County of Odaho )ss.:  On this oday of Management of the individual of instrument, and acknowledged execution of	, 1998, before me personally came David R described in and who executed the foregoing the same.
* HOTARL	Notary Public

Willard L. Hofer

Date: 5/5/98

United States of America )
State of <u>John )ss.:</u>
County of <u>Oda</u> )

On this 5 day of \_\_\_\_\_\_, 1998, before me personally came Willard L. Hofer, to me known to be the individual described in and who executed the foregoing instrument, and acknowledged execution of the same.

Notary Public